

## Boundary Conduction Mode Power Factor Correction Controller IC

## BD7693FJ BD7694FJ

#### **General Description**

BD7693FJ and BD7694FJ are Power Factor Correction IC for AC/DC supplies the system which is suitable for all the products needing power factor improvement. The PFC adopts boundary conduction mode (BCM), and switching loss reduction and noise reduction are possible by Zero Current Detection (ZCD). This IC incorporates a circuit lowering total harmonics distortion (THD) and can support IEC61000-3-2 Class-C.

#### Features

- Boundary Conduction Mode PFC
- Low THD Circuit Incorporation
- Low Power Consumption
- VCC UVLO Function
- ZCD by Auxiliary Winding
- Static OVP by the VS Pin
- Error Amplifier Input Short Protection
- Stable MOSFET Gate Drive
- Soft Start

#### Applications

 Lighting Equipment, AC Adopter, TV, Refrigerator, etc.

## **Typical Application Circuit**

#### Key Specifications

- Input VCC Voltage Range: 10 V to 38 V
- Operating Current: 0.58 mA (Typ)
- Operating Temperature Range: -40 °C to +105 °C

## Package

## SOP-J8

#### W (Typ) x D (Typ) x H (Max) 4.9 mm x 6.0 mm x 1.65 mm



#### Lineup

icup	
Product name	Brown Out
BD7693FJ-E2	-
BD7694FJ-E2	0



OProduct structure : Silicon integrated circuit OThis product has no designed protection against radioactive rays.

## **Pin Configuration**

(TOP VIEW)



#### **Pin Description**

Pin No.	Pin Name	I/O	Function	ESD I	Diode
FILLINO.	FILINALLE	1/O	FUICION	VCC	GND
1	VS	I	Feedback input pin	-	0
2	EO	0	Error amplifier output pin	-	0
3	MULT	Ι	Multiplier input pin	-	0
4	CS		Over current detection pin	-	0
5	ZCD	I	Zero current detection pin	-	0
6	GND	-	GND pin	0	-
7	OUT	0	External MOSFET driver pin	-	0
8	VCC	I	Power supply pin	-	0

## **Block Diagram**



## **Description of Blocks**

#### 1 VCC Protection

This IC has VCC UVLO (Under Voltage Lock Out) of the VCC pin. Switching stops at the time of VCC voltage drop. In addition, when the VCC voltage becomes higher than the  $V_{CC_{DIS1}}$  (38 V Typ) voltage, it increases operating current and suppresses the rise in VCC voltage. When the VCC voltage lowers than the  $V_{CC_{DIS2}}$  (34 V Typ) voltage, the operating current becomes usual. This function assumes the case that the VCC voltage rises by startup resistance.

#### 2 PFC: Power Factor Correction

The power factor improvement circuit is a voltage control method of Boundary Conduction Mode. The outline operation circuit diagram is shown in Figure 1. The switching operation is shown in Figure 2.





Figure 2. Switching Operation Timing Chart

#### Switching Operation

1. MOSFET is turned on, and  $I_{L}$  increases.

1

- 2. The IC compares Multiplier out with  $V_{CS}$  slope, and MOSFET is off when the  $V_{CS}$  voltage higher than Multiplier out.
- 3. MOSFET is off, and  $I_{L}$  decreases.

Vzcd

4. The ZCD pin detects a zero point of the  $\mathsf{I}_\mathsf{L}$  and turns on MOSFET.

#### 3 About ErrAMP

#### 3.1 GmAMP

The VS pin monitors a divided point for resistance of the output voltage. The ripple voltage of AC frequency (50 Hz / 60 Hz) overlaps with the VS pin. GmAMP removes this ripple voltage. GmAMP compares  $V_{AMP1}$  (2.500 V Typ) with the removed voltage, GmAMP controls the EO voltage by this gap. When the EO pin voltage rises, ON width of the OUT pin becomes wide. When the EO voltage less than  $V_{BURST}$  (1.9 V Typ), the IC stops switching. Therefore, it can stop switching operation when the EO pin connects to the GND.

Also, you must set the error amplifier constant so that the AC frequency does not overlap on the EO pin. And, please confirm it by an actual board.





#### 3.2 VS Short Protection

The VS pin has a short protection function.

A state of the VS pin voltage <  $V_{SHORT}$  (0.3 V Typ) continues  $t_{VS_SH}$  (150 µs Typ) or more, it stops switching. Figure 4 shows the operation.





#### 3 About ErrAMP - continued

#### 3.3 VS Overvoltage Protection Function (SOVP)

The VS pin voltage rises from V<sub>OVP1</sub> (2.7 V Typ), it stops switching immediately. The VS pin voltage less than V<sub>OVP2</sub> (2.6 V Typ), it starts switching. Figure 5 shows the operation.



Figure 5. VS Overvoltage Protection Operation

#### 3.4 Over Voltage Reduce Function at Start Up (OVR)

When the VS pin voltage performs a rise in startup to  $V_{OVR}$  (2.25 V Typ) (equivalent to -10 % of output voltage), it discharges the EO voltage to the  $V_{BURST}$  forcibly. OUT pulse width is narrows when the EO voltage falls, through rate of output voltage becomes slow and reduces over voltage in the startup. This function is effective only once after VCC UVLO cancellation.

#### 4 ZCD pin

The zero current detection circuit is a function to detect a zero cross of the inductor current ( $I_L$ ) (Figure 6, 7). If the voltage at the ZCD pin becomes lower than  $V_{ZCD2}$  (0.67 V Typ) after becoming higher than  $V_{ZCD1}$  (0.9 V Typ), the OUT output becomes High after the ZCD output delay time ( $t_{ZCD}$  260 ns Typ) has elapsed. When the ZCD voltage does not reach  $V_{ZCD1}$  (0.9 V Typ), it becomes the restart timer operation. After the OUT output becomes High after  $t_{REST}$  (30 µs Typ) progress (Figure 8).



Figure 6. Zero Current Detection Circuit





Figure 8. Restart Timer

#### 5 MULTIPLIER

The ON width of the OUT pin is fixed in Multiplier out and  $V_{CS}$  as it showed in Figure 2.  $V_{CS}$  is expressed in the following formula.

$$V_{CS} = K \times V_{MULT}(V_{EO} - V_{BURST})$$

K:	MULTIPLIER GAIN
VMULT:	MULT pin voltage
VEO:	EO pin voltage
VBURST:	Burst voltage

AC voltage information is input into  $V_{MULT}$ . The IC improves a power factor by controlling AC current with the AC voltage. In addition,  $V_{CS}$  in AC voltage 0 V ( $V_{MULT}$  = 0 V) is expressed in the following formula.

 $V_{CS} = K \times V_{MULT}(V_{EO} - V_{BURST}) + V_{OFFSET} = V_{OFFSET}$ 

The ON width of the OUT pin at the age of AC voltage 0 V ( $V_{MULT} = 0$  V) becomes long by adding  $V_{OFFSET}$  (25 mV Typ). Because ON width gets longer, diode bridge output voltage is discharged. As a result, an AC current distortion is improved without the current supply from a diode bridge stopping (Figure 9).



Figure 9. Improvement of the AC Current Distortion

## 6 MULT pin

When the state that the MULT pin voltage is lower than  $V_{BROUT1}$  (0.8 V Typ) continues  $t_{BROUT}$  (160 ms Typ) or more, the IC stops switching by a brown out function (only in BD7694). When the MULT pin voltage becomes higher than  $V_{BROUT2}$  (0.97 V Typ), the IC switches again.

hen the MULI pin voltage becomes higher than  $V_{BROUT2}$  (0.97 V Typ), the IC switches again.



Figure 10. Brown Out

#### 7 CS pin

In normal operation, turn OFF of the switching is usually decided by ON width by the EO pin and the MULT pin voltage. However, the IC is off in a pulse by pulse in overcurrent protection when the CS pin rises than  $V_{CS}$  (1.5 V Typ). By this protection, it prevents an overcurrent to MOSFET.

The overcurrent protection function limits ON width. When this protection becomes the working PFC load, PFC output voltage decreases. You must decide sense resistance of PFC so that this protection does not work in rated load with the minimum input voltage at the time of the application design.



Figure 11. Current Limit

## **Operation Mode of Protection Circuit**

Table 1 showed the operation mode of each protection function.

			Protectio	on Mode	
Parameter	Contents	Detection Method	Detection Operation	Cancellation Method	Cancellation Operation
VCC UVLO	Under Voltage Lock Out on the VCC pin	VCC < 8 V (Typ) (VCC drop)	OUT OFF EO discharge	VCC > 13 V (Typ) (VCC rise)	Startup Operation
CS OCP	Over Current Protection on the CS pin	CS > 1.5 V (Typ) (CS rise)	OUT OFF	CS < 1.5 V (Typ) (CS drop)	Normal Operation
VS Short	Short Protection on the VS pin	VS < 0.3 V (Typ) (VS drop)	OUT OFF EO discharge	VS > 0.3 V (Typ) (VS rise)	Normal Operation
VS Static OVP	Over Voltage Protection on the VS pin	VS > 2.7 V (Typ) (VS rise)	OUT OFF	VS < 2.6 V (Typ) (VS drop)	Normal Operation
Brown Out (Only BD7694)	Low Voltage Protection on the MULT pin	MULT < 0.8 V (Typ) (MULT drop)	OUT OFF EO discharge	MULT > 0.97 V (Typ) (MULT rise)	Normal Operation

Table 1	Operation	Mode of F	ach Protectiv	/e Circuit
Tuble 1.	operation	Mode of E		o on our

### Absolute Maximum Ratings (Ta = 25 °C)

Parameter	Symbol	Rating	Unit	Condition
Maximum Voltage 1	V <sub>MAX1</sub>	-0.3 to +40	V	VCC
Maximum Voltage 2	V <sub>MAX2</sub>	-0.3 to +14	V	OUT
Maximum Voltage 3	V <sub>MAX3</sub>	-0.3 to +6.5	V	CS, MULT, VS, EO
Maximum Current 1	IZCD1	-10 to +10	mA	ZCD current
OUT Pin Output Peak Current 1	IOUT1	-0.5	Α	Source current
OUT Pin Output Peak Current 2	I <sub>OUT2</sub>	+1	Α	Sink current
Maximum Junction Temperature	Tjmax	+150	°C	
Storage Temperature Range	Tstg	-55 to +150	°C	

Caution 1: Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

Caution 2: Should by any chance the maximum junction temperature rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. In case of exceeding this absolute maximum rating, design a PCB with thermal resistance taken into consideration by increasing board size and copper area so as not to exceed the maximum junction temperature rating.

#### Thermal Resistance<sup>(Note 1)</sup>

C: maked	Thermal Res	1.1	
Symbol	1s <sup>(Note 3)</sup>	2s2p <sup>(Note 4)</sup>	Unit
Αιθ	149.3	76.9	°C/W
$\Psi_{JT}$	18	11	°C/W
		Symbol         1s <sup>(Note 3)</sup> θJA         149.3	θJA         1s <sup>(Note 3)</sup> 2s2p <sup>(Note 4)</sup>

(Note 1) Based on JESD51-2A(Still-Air)

(Note 2) The thermal characterization parameter to report the difference between junction temperature and the temperature at the top center of the outside surface of the component package.

(*Note 3*) Using a PCB board based on JESD51-3. (*Note 4*) Using a PCB board based on JESD51-7.

Layer Number of Measurement Board	Material	Board Size
Single	FR-4	114.3 mm x 76.2 mm x 1.57 mmt
Тор		
Copper Pattern	Thickness	
Footprints and Traces	70 µm	

Layer Number of Measurement Board	Material	Board Size			
4 Layers	FR-4	114.3 mm x 76.2 mm x 1.6 mmt			
Тор		2 Internal Layers		Bottom	
Copper Pattern	Thickness	Copper Pattern Thickness		Copper Pattern	Thickness
Footprints and Traces	70 µm	74.2 mm x 74.2 mm	35 µm	74.2 mm x 74.2 mm	70 µm

#### **Recommended Operating Conditions**

Parameter	Symbol	Min	Тур	Max	Unit	Condition
Supply Voltage	VCC	10	15	38	V	VCC Voltage
Operating Temperature	Topr	-40	+25	+105	С°	

#### Recommended Range of the External Component (Ta = 25 °C)

Parameter	Symbol	Rating	Unit
VCC Pin Connection Capacity	Cvcc	22 or more	μF

## Electrical Characteristics (Unless otherwise specified VCC = 15 V, Ta = -40 °C to +105 °C)

Electrical Characteristics (Of	1633 Other W	lise speci	ieu voo -	15 V, 1a -	-40 010	+105 C)
Parameter	Symbol	Min	Тур	Max	Unit	Condition
[Circuit Current]						
Circuit Current (ON) 1	Ion1	-	0.58	1.20	mA	VS = 0 V
	IONT	_	0.00	1.20		VO - 0 V
Circuit Current (ON) 2	lon2	-	0.95	2.00	mA	50 kHz switching
Circuit Current (ON) 3	Іолз	4.5	9.0	13.5	mA	VCC discharge Switching stop
Start Up Current	Istart	-	100	200	μA	VCC = 12 V
[VCC Pin Protection]						
VCC UVLO Voltage1	VUVLO1	12	13	14	V	VCC rise
VCC UVLO Voltage2	VUVLO2	7	8	9	V	VCC drop
VCC UVLO Hysteresis	Vuvlo3	3.8	5.0	6.2	V	VUVLO3 = VUVLO1 - VUVLO2
VCC Discharge Voltage1	Vcc_DIS1	-	38	-	V	VCC rise
VCC Discharge Voltage2	V <sub>CC_DIS2</sub>	-	34	-	V	VCC drop
[Gm Amplifier Block]	T	1	1	T		
VS Pin Pull-up Current	lvs	-	0.1	0.5	μA	VS = 0 V
Gm Amplifier	VAMP1	2.465	2.500	2.535	V	Ta = 25 °C
Reference Voltage1	- /				-	
Gm Amplifier Reference Voltage2	VAMP2	2.44	-	2.54	V	Ta = -40 °C to +105 °C
Gm Amplifier Line Regulation	VAMP LINE	-	1	10	mV	VCC = 10 V to 38 V
Gm Amplifier	Tvs	80	100	130	μΑ/V	EO = 2.5 V, Ta = 25 °C
Trans Conductance	-				•	
Gm Amplifier Source Current	IEO_SOURCE	5	10	20	μA	VS = 2.3 V
Gm Amplifier Sink Current	IEO_SINK	5	10	20	μA	VS = 2.7 V
[EO Block]		1				
EO L Voltage	VEOL	-	1.6	1.8	V	VS = 2.7 V
Burst Voltage	VBURST	1.8	1.9	-	V	
EO Discharge Current [MULT Block]	I <sub>EO</sub>	0.8	1.8	3.0	mA	VCC = 12 V, EO = 1.0 V
MULT Pin Pull-up Current	Imult	-	0.1	0.5	μA	MULT = 0 V
MULT Pin Dynamic Range	VMULT	0 to 2.5	0 to 3.5	-	V V	
	VINULI	VBURST	VBURST	_	v	
EO Pin Dynamic Range	VEOD	to	to	-	V	
	VLOD	2.9	3.4		· ·	
MULTIPLIER Gain	K	0.43	0.65	0.87	1/V	MULT = 0.5 V, EO = 3.0 V
Brown Out Detect Voltage1	VBROUT1	0.7	0.8	0.9	V	MULT drop
g.					-	BD7694FJ Only
Brown Out Detect Voltage2	VBROUT2	0.87	0.97	1.07	V	MULT rise BD7694FJ Only
Brown Out Detect Timer	<b>t</b> BROUT	80	160	320	ms	BD7694FJ Only
[ZCD Block]	BROOT			020		00 0 0y
ZCD Threshold Voltage1	V <sub>ZCD1</sub>	0.8	0.9	1.0	V	ZCD rise
ZCD Threshold Voltage2	VZCD2	0.55	0.67	0.79	V	ZCD drop
ZCD Output Delay	tzcp	-	260	520	ns	•
Input H Clamp Voltage	VIH	6.1	6.7	-	V	lsink = 3 mA
Input L Clamp Voltage	VIL	-0.3	-0.1	-	V	Isource = -3 mA
Restart Timer	tREST	15	30	45	μs	
[VS Protection Block]					· · ·	
VS Short Protection Detection Voltage	V <sub>SHORT</sub>	0.2	0.3	0.4	V	
VS Shortstop Protection	4	50	450	000		
Detection Time	tvs_sн	50	150	300	μs	
	_			1		
			0.9 x		N /	
Over Voltage Reduce Detection Voltage	Vovr	-	0.9 x Vamp1	-	V	
Over Voltage Reduce Detection		- 1.065 x		- 1.095 x	-	$VS$ riso $T_{0} = 25$ °C
Over Voltage Reduce Detection Voltage VS Overvoltage Protection Detection Voltage 1	Vovr Vovp1	VAMP1	VAMP1 1.080 x VAMP1	VAMP1	V V	VS rise Ta = 25 °C
Over Voltage Reduce Detection Voltage VS Overvoltage Protection			V <sub>AMP1</sub> 1.080 x		-	VS rise Ta = 25 °C VS drop Ta = 25 °C

## Electrical Characteristics (Unless otherwise specified VCC = 15 V, Ta = -40 °C to +105 °C) - continued

Parameter	Symbol	Min	Тур	Max	Unit	Condition
[CS Block]	L.	l	1			J
CS Threshold Voltage	Vcs	1.3	1.5	1.8	V	
Output Delay Time	t <sub>DELAY</sub>	-	150	300	ns	
CS Pin Pull-up Current	Ics	-	0.15	1.00	μA	CS = 0 V
CS Offset Voltage	VOFFSET	-	25	-	mV	MULT = 0 V
[OUT Block]						
OUT H Voltage	VPOUTH	9.0	10.2	11.4	V	OUT = -20 mA
OUT L Voltage	VPOUTL	-	-	0.8	V	OUT = +20 mA
Rise Time	tr	-	50	-	ns	OUT load capacitor = 1000 pF OUT L Voltage to 5 V
Fall Time	tf	-	50	-	ns	OUT load capacitor = 1000 pF OUT H Voltage to 5 V
OUT Pull-down Resistance	Rpdout	50	100	150	kΩ	

## **Typical Performance Curves**

(Reference data)



Figure 12. Vcs vs VMULT



Figure 13. Gm Amplifier Reference Voltage1 vs Temperature



Figure 14. Gm Amplifier Reference Voltage1 vs VCC

## **Typical Performance Curves - continued**



Figure 15. VS Overvoltage Protection Detection Voltage1 vs Temperature



Figure 17. VCC UVLO Voltage vs Temperature



Figure 16. Start Up Current vs Temperature



Figure 18. OUT H Voltage vs VCC

## **Application Example**



Figure 19. Application Example

#### 1 Output Voltage Setting

The output voltage is decided on feedback resistance by the VS pin.

$$V_{OUT} = \left(1 + \frac{(R_{17} + R_{18})}{(R_{19}//R_{20})}\right) \times V_{AMP} = \left(1 + \frac{1582 \, k\Omega}{10 \, k\Omega}\right) \times 2.5 \, V = 398 \, \text{[V]}$$

 $R_{17} + R_{18}$ :Upper side resister of the output feedback $R_{19}//R_{20}$ :Bottom side resister of the output feedback $V_{AMP}$ :Gm amplifier reference voltage1

#### 2 Calculation of the Inductance

Reference value in case of V<sub>OUT</sub> = 400 V, Output power = 200 W

L = 250 [µH]

Setting a large value of inductance will reduce the THD but increase the component size.

#### 3 External Parts of VCC

The VCC pin can reduce VCC voltage change at the time of the switching by attaching capacitor.

This IC drives gate capacitor of the external MOSFET by the OUT pin. The VCC capacitor recommends electric field capacitor 22  $\mu$ F or more withstand pressure 50 V or more.

In addition, you must confirm VCC voltage evaluation at the time of startup and the protection detection with an actual board when VCC is generated by startup resistance and the auxiliary winding of the transformer.

Because the consumption current of the IC decreases when an IC becomes the switching stop state after startup, the VCC voltage may rise by startup resistance. The overvoltage destruction of VCC is prevented by VCC voltage discharge function. The startup resistor value makes small by this function, boot-time becomes fast.

## Attention in the Board Design

About parts placement

You must locate the parts in the Figure 20 inside dot line near the IC. In addition, please do parts placement to avoid the interference with switching lines and high current lines such as inductor, DRAIN.



Figure 20. Parts Placement

About GND wiring guidance

The red line of Figure 21 is the GND lines which large current flows. Draw each line as an independent wire. In addition, pull the wiring thick and short. The blue line is the GND of the IC. Make the GND of the IC and the GND of the peripheral parts common.



Figure 21. GND Line Layout

## Attention in the Board – continued

About large current line

Large circuit current flows through the part of the red line of Figure 22. You must wire it short and thickly. Do not place IC and high impedance line near the red line because it has large noise.



Figure 22. High Current Line Layout

## I/O Equivalence Circuits



#### **Operational Notes**

#### 1. Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply pins.

#### 2. Power Supply Lines

Design the PCB layout pattern to provide low impedance supply lines. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

#### 3. Ground Voltage

Except for pins the output and the input of which were designed to go below ground, ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

#### 4. Ground Wiring Pattern

When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

#### 5. Recommended Operating Conditions

The function and operation of the IC are guaranteed within the range specified by the recommended operating conditions. The characteristic values are guaranteed only under the conditions of each item specified by the electrical characteristics.

#### 6. Inrush Current

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

#### 7. Testing on Application Boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

#### 8. Inter-pin Short and Mounting Errors

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

#### 9. Unused Input Pins

Input pins of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input pins should be connected to the power supply or ground line.

#### **Operational Notes – continued**

#### 10. Regarding the Input Pin of the IC

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of the P layers with the N layers of other elements, creating a parasitic diode or transistor. For example (refer to figure below):

When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode. When GND > Pin B, the P-N junction operates as a parasitic transistor.

Parasitic diodes inevitably occur in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the P substrate) should be avoided.



Figure 23. Example of Monolithic IC Structure

#### 11. Ceramic Capacitor

When using a ceramic capacitor, determine a capacitance value considering the change of capacitance with temperature and the decrease in nominal capacitance due to DC bias and others.

#### 12. Thermal Shutdown Circuit (TSD)

This IC has a built-in thermal shutdown circuit that prevents heat damage to the IC. Normal operation should always be within the IC's maximum junction temperature rating. If however the rating is exceeded for a continued period, the junction temperature (Tj) will rise which will activate the TSD circuit that will turn OFF power output pins. When the Tj falls below the TSD threshold, the circuits are automatically restored to normal operation.

Note that the TSD circuit operates in a situation that exceeds the absolute maximum ratings and therefore, under no circumstances, should the TSD circuit be used in a set design or for any purpose other than protecting the IC from heat damage.

#### 13. Over Current Protection Circuit (OCP)

This IC incorporates an integrated overcurrent protection circuit that is activated when the load is shorted. This protection circuit is effective in preventing damage due to sudden and unexpected incidents. However, the IC should not be used in applications characterized by continuous operation or transitioning of the protection circuit.

## **Ordering Information**



## E 2

Packaging and forming specification E2: Embossed tape and reel

## Marking Diagram



Product name	Part Number Marking		
BD7693FJ-E2	D7693		
BD7694FJ-E2	D7694		

## Datasheet

#### **Physical Dimension and Packing Information**



## **Revision History**

· • .			
	Date	Revision	Changes
	25.Nov.2020	001	New Release

# Notice

#### Precaution on using ROHM Products

1. Our Products are designed and manufactured for application in ordinary electronic equipment (such as AV equipment, OA equipment, telecommunication equipment, home electronic appliances, amusement equipment, etc.). If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment (<sup>Note 1)</sup>, transport equipment, traffic equipment, aircraft/spacecraft, nuclear power controllers, fuel controllers, car equipment including car accessories, safety devices, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

(Note1) Medical Equipment Classification of the Specific Applications
---

JAPAN	USA	EU	CHINA
CLASSⅢ	CLASSI	CLASS II b	CLASSII
CLASSⅣ	CLASSII	CLASSⅢ	CLASSI

- 2. ROHM designs and manufactures its Products subject to strict quality control system. However, semiconductor products can fail or malfunction at a certain rate. Please be sure to implement, at your own responsibilities, adequate safety measures including but not limited to fail-safe design against the physical injury, damage to any property, which a failure or malfunction of our Products may cause. The following are examples of safety measures:
  - [a] Installation of protection circuits or other protective devices to improve system safety
  - [b] Installation of redundant circuits to reduce the impact of single or multiple circuit failure
- 3. Our Products are designed and manufactured for use under standard conditions and not under any special or extraordinary environments or conditions, as exemplified below. Accordingly, ROHM shall not be in any way responsible or liable for any damages, expenses or losses arising from the use of any ROHM's Products under any special or extraordinary environments or conditions. If you intend to use our Products under any special or extraordinary environments or conditions (as exemplified below), your independent verification and confirmation of product performance, reliability, etc, prior to use, must be necessary:
  - [a] Use of our Products in any types of liquid, including water, oils, chemicals, and organic solvents
  - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
  - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
  - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
  - [f] Sealing or coating our Products with resin or other coating materials
  - [g] Use of our Products without cleaning residue of flux (Exclude cases where no-clean type fluxes is used. However, recommend sufficiently about the residue.); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
  - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse, is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

#### Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

#### Precautions Regarding Application Examples and External Circuits

- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
- 2. You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

#### **Precaution for Electrostatic**

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

#### Precaution for Storage / Transportation

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
  - [a] the Products are exposed to sea winds or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [b] the temperature or humidity exceeds those recommended by ROHM
  - [c] the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

#### **Precaution for Product Label**

A two-dimensional barcode printed on ROHM Products label is for ROHM's internal use only.

#### Precaution for Disposition

When disposing Products please dispose them properly using an authorized industry waste company.

#### Precaution for Foreign Exchange and Foreign Trade act

Since concerned goods might be fallen under listed items of export control prescribed by Foreign exchange and Foreign trade act, please consult with ROHM in case of export.

#### **Precaution Regarding Intellectual Property Rights**

- 1. All information and data including but not limited to application example contained in this document is for reference only. ROHM does not warrant that foregoing information or data will not infringe any intellectual property rights or any other rights of any third party regarding such information or data.
- 2. ROHM shall not have any obligations where the claims, actions or demands arising from the combination of the Products with other articles such as components, circuits, systems or external equipment (including software).
- 3. No license, expressly or implied, is granted hereby under any intellectual property rights or other rights of ROHM or any third parties with respect to the Products or the information contained in this document. Provided, however, that ROHM will not assert its intellectual property rights or other rights against you or your customers to the extent necessary to manufacture or sell products containing the Products, subject to the terms and conditions herein.

#### **Other Precaution**

- 1. This document may not be reprinted or reproduced, in whole or in part, without prior written consent of ROHM.
- 2. The Products may not be disassembled, converted, modified, reproduced or otherwise changed without prior written consent of ROHM.
- 3. In no event shall you use in any way whatsoever the Products and the related technical information contained in the Products or this document for any military purposes, including but not limited to, the development of mass-destruction weapons.
- 4. The proper names of companies or products described in this document are trademarks or registered trademarks of ROHM, its affiliated companies or third parties.

#### **General Precaution**

- 1. Before you use our Products, you are requested to carefully read this document and fully understand its contents. ROHM shall not be in any way responsible or liable for failure, malfunction or accident arising from the use of any ROHM's Products against warning, caution or note contained in this document.
- 2. All information contained in this document is current as of the issuing date and subject to change without any prior notice. Before purchasing or using ROHM's Products, please confirm the latest information with a ROHM sales representative.
- 3. The information contained in this document is provided on an "as is" basis and ROHM does not warrant that all information contained in this document is accurate and/or error-free. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties resulting from inaccuracy or errors of or concerning such information.